Modeling and control of Transparent Conducting Oxide layer surface morphology for improved light trapping

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Abstract

This work first introduces a kinetic Monte–Carlo simulation model for a two species thin film deposition process and demonstrates the use of feedback control, coupled with a suitable actuator design, in manufacturing thin films whose surface morphology has a structure that improves light trapping. This work is relevant in the context of a Transparent Conducting Oxide (TCO) thin film layer manufacturing used in thin film solar cells where it is desirable to produce thin films with precisely tailored surface morphology. Specifically, a two species thin film deposition process involving atom adsorption, surface relaxation and surface migration is initially considered and is modeled using a large-lattice (lattice size≈40,000) kinetic Monte–Carlo simulation. Subsequently, thin film surface morphology characteristics like roughness and slope are computed with respect to different characteristic length scales ranging from atomic to the ones corresponding to visible light wavelength and it is found that a patterned actuator design is needed to induce thin film surface roughness and slope at visible light wavelength spatial scales, that lead to desired thin film solar cell performance. Then, an Edwards–Wilkinson type equation is used to model the surface evolution at the visible light wavelength spatial scale and form the basis for the design of a predictive feedback controller whose objective is to manipulate the deposition rate across the spatial domain of the process. The model parameters of the Edwards–Wilkinson equation are estimated from kinetic Monte–Carlo simulations and their dependence on the deposition rate is used in the formulation of the predictive controller to predict the influence of the control action on the surface roughness and slope throughout the thin film growth process. Analytical solutions of the expected surface roughness and surface slope at the visible light wavelength spatial scale are obtained by solving the Edwards–Wilkinson equation and are used in the predictive controller formulation and in the control action calculation. The controller is applied to the large-lattice kinetic Monte–Carlo simulation. Simulation results demonstrate that the proposed controller and patterned actuator design successfully regulate aggregate surface roughness and slope to set-point values at the end of the deposition.

1. Introduction

Thin film solar cells constitute an important and growing component of the overall solar cell market (see, for example, Green, 2007; van Sark et al., 2007) owing to the potential of improved light conversion efficiencies (currently on the order of 10% for production modules). The Transparent Conducting Oxide (TCO) layer, which typically consists of zinc oxide (ZnO) and aluminum (Al), is an important component of thin film solar cells and has a crucial influence on the performance of thin film solar cell systems (see, for example, Krč and Zeman, 2003; Gospodyn and Sit, 2006). In addition to investigating the performance with respect to light conversion efficiency and long-term stability of an array of materials, thin film solar cell technology stands to benefit from optimal thin film manufacturing (deposition) control strategies that produce thin films with desired light trapping properties. Specifically, extensive research on optical properties of thin-film TCO layers has demonstrated that the surface morphology at the interface, which is characterized by surface roughness and slope, directly influences the efficiency of thin-film silicon solar cells (see, for example, Gospodyn and Sit, 2006; Krč and Zeman, 2003; Zeman and Vanswaaij, 2000; Poruba et al., 2000; Muller and Rech, 2004; Rowlands et al., 2004). Shaping the surface morphology of the TCO layer at the thin film deposition stage is therefore critical in order to maximize the amount of light converted to electrical energy. While developing accurate models for predicting optical properties of TCO thin films is an on-going research topic, it is...
well-established that the root-mean-square surface roughness and slope at characteristic length scales that are comparable to the wavelength of the visible light are key factors that influence thin film optical properties (e.g., Huang et al., 2011b; Krč and Zeman, 2003). Despite the importance of these efforts and the broad realization that the surface morphology of the TCO layer could be tailored to improve thin film solar cell efficiency, the problem of shaping the TCO thin film surface morphology during film deposition by appropriately controlling the surface slope and roughness to desired levels has received limited attention. Thus, it is desirable to develop systematic approaches to manufacture thin film solar cells with optimal light conversion efficiencies via computational multi-scale modeling and real-time model-based control of the manufacturing process.

Over the last 20 years within the control engineering literature, extensive efforts have been made on the modeling and model-based feedback control of thin film deposition processes with emphasis on the problems of film thickness, roughness and porosity regulation. Microscopic modeling of thin film growth is usually carried out via kinetic Monte–Carlo (kMC) methods (see, for example, Gillespie, 1976; Reese et al., 2001; Christofides et al., 2008 for results and references in this area) as well as stochastic partial differential equations (e.g., Edwards and Wilkinson, 1982; Vvedensky et al., 1993; Laurant et al., 1996). With respect to model-based feedback control of thin film deposition, early efforts focused on deposition spatial uniformity control on the basis of continuum-type distributed parameter models (e.g., Christofides, 2001), while within the last 10 years, most attention has focused on control of thin film surface morphology and microstructure. Since kMC models are not available in closed form and cannot be readily used for feedback control design and system-level analysis, stochastic differential equation (SDE) models (whose parameters are computed from kMC model data) have been used as the basis for the design of feedback controllers to regulate thin film surface roughness (e.g., Christofides et al., 2008; Ni and Christofides, 2005; Varshney and Armaou, 2005, 2006; Hu et al., 2009a), film porosity (Hu et al., 2009a,b), and film thickness. In an attempt to manufacture thin film solar cells with optimal light conversion efficiencies, we previously conducted research on the modeling and control of silicon thin film surface morphology to optimize thin film light trapping properties (Huang et al., 2011b, 2012), both at the atomic level and at an aggregated level comparable to the visible light wavelength (Huang et al., 2011b; Zhang et al., 2012).

Motivated by the above considerations, in the present paper, we focus on the application of microscopic modeling and control to the process of TCO thin film deposition, which consists of ZnO and Al. Specifically, this work introduces a two species simulation for TCO layer deposition process and presents an integrated control actuator and control algorithm design framework for the regulation of deposition of TCO thin films such that the final thin film surface morphology is controlled to a desired level. To demonstrate the approach, we focus on a two species thin film deposition process using a large-lattice (lattice size = 40,000) kinetic Monte–Carlo simulation. Different deposition mechanisms are utilized for each component, ZnO and Al. Specifically, random deposition with surface relaxation (RDSR) mechanism is used for Al and deposition/migration mechanism is used for ZnO (Huang et al., 2010). Subsequently, surface roughness and slope at different length-scales ranging from atomic scale to visible light wavelength scale are both calculated based on the generated thin film surface. It is found that a patterned actuator design is needed to induce thin film surface roughness and slope at visible light wavelength spatial scales to desired levels. Since a large-lattice kinetic Monte–Carlo model cannot be used as the basis for controller design and real-time controller calculations, an Edwards–Wilkinson type equation is used to model the surface evolution at the visible light wavelength spatial scale and to form the basis for feedback controller design within a model predictive control framework. The cost function of the predicted controller involves penalties on both surface roughness and slope from set-point values as well as constraints on the magnitude and rate of change of the control action. The Edwards–Wilkinson equation model parameters are estimated from kinetic Monte–Carlo simulations and their dependence on the manipulated input (deposition rate) is used to predict the influence of the control action on the surface roughness and slope during the growth process. The controller formulation takes advantage of analytical solutions of the expected surface roughness and surface slope at the visible light wavelength spatial scale and the controller is applied to the large-lattice kinetic Monte–Carlo simulation. Extensive simulation studies demonstrate that the proposed controller and patterned actuator design successfully regulate surface roughness and slope at visible light wavelength spatial scales to set-point values at the end of the deposition.

### 2. Two species thin film deposition process description and modeling

In this section, a one-dimensional solid-on-solid (SOS) on-lattice kinetic Monte–Carlo (kMC) model is used to simulate the two species thin film deposition process, which includes three microscopic processes: an adsorption process, in which particles are incorporated into the film from the gas phase, a migration process and a surface relaxation process, in which surface particles move to adjacent sites (Levine et al., 1998; Levine and Clancy, 2000; Wang and Clancy, 2001; Yang et al., 1997). The model is valid for temperatures $T < 0.5T_m$, where $T_m$ is the melting point of the deposited material (Levine et al., 1998). At high temperatures ($0.5T_m \leq T \leq T_m$), the particles cannot be assumed to be constrained on the lattice sites and the on-lattice model may not be valid. In this work, a square lattice is selected to represent the structure of the film, as shown in Fig. 1. All particles are modeled as identical hard spheres and the centers of the particles deposited on the film are located on the lattice sites. The diameter of the particles equals the distance between two neighboring sites. The width of the lattice is fixed so that the lattice contains a fixed number of sites in the lateral direction. The new particles are always deposited from the top side of the lattice with vertical incidence; see Fig. 1. Particle deposition results in film growth in the direction normal to the lateral direction. The direction normal to the lateral direction is thus designated as the growth direction. The number of sites in the lateral direction is defined as the lattice size and is denoted by $L$. Periodic boundary conditions (PBCs) are applied at the edges of the lattice in the lateral direction.

The top particles of each column are defined as the surface particles and the positions of the centers of all surface particles form the surface height profile. The number of nearest neighbors of a surface particle ranges from zero to two. A surface particle with zero nearest neighbors is possible to move to one of its adjacent columns with equal probability. A surface particle with one nearest neighbor is possible to move to its adjacent column with lower height. A surface particle with two nearest neighbors cannot move. Particles that are not on the film surface cannot move.

The overall deposition rate, $w$, is expressed in the unit of layer per second and is a combination of two components, ZnO deposition rate $w_1$ and Al deposition/migration rate $w_2$ ($w = w_1 + w_2$). The deposition ratio between ZnO and Al is 24:1 (Das et al., 2005). Different deposition mechanisms are used for each component. Random deposition with surface relaxation (RDSR) mechanism is used for Al. Specifically, in the RDSR process a site is randomly selected with uniform probability among all lattice sites and a particle is deposited on the top of this site. If the just deposited particle has less than two nearest neighbors, it will move according to the rules described above. A deposition/migration mechanism is used for ZnO. In this model, the...
deposition and migration events are separate and independent microscopic events. The deposition event is a random process, i.e., the same random deposition (without surface relaxation) as in the RDSR model. However, the migration event does not follow immediately the deposition of the particle. Instead, each surface particle, i.e., the top particle of a lattice site, is subject to its own migration event with a probability that depends on its local environment and the substrate temperature. The migration rate (probability) follows an Arrhenius-type law with a pre-calculated activation energy barrier that depends on the local environment of the particle, i.e., the number of the nearest neighbors of the particle chosen for a migration event. The migration rate of the \( i \)-th surface particle is calculated as follows:

\[
r_m = v_0 \exp \left( \frac{-E_a + n_i E_n}{k_B T} \right)
\]

where \( v_0 \) denotes the pre-exponential factor, \( n_i \) is the number of the nearest neighbors of the \( i \)-th particle and can take the values of 0 and 1, \( (r_m \) is zero when \( n_i=2 \) since in the one-dimensional lattice this surface particle is fully surrounded by other particles and cannot migrate), \( k_B \) is the Boltzmann's constant, \( E_a \) is the contribution to the activation energy barrier from the site itself, and \( E_n \) is the contribution to the activation energy barrier from each nearest neighbor. In this work, \( E_a = 3.4 \text{ eV} \) and \( E_n = 0 \text{ eV} \). (Moller and Palumbo, 2001). \( T \) is the substrate temperature of the thin film and in this work \( T=800 \text{ K} \) (Mirica et al., 2004). Since the film is thin, the temperature is assumed to be uniform throughout the film. For the detailed description and investigation of these models, refer to Huang et al. (2010).

2.1. Surface morphology at atomic level

Thin film surface morphology, which can be expressed in terms of surface roughness and slope, is a very important surface property influencing the light properties of TCO thin films. Surface roughness is defined as the root-mean-square (RMS) of the surface height profile. Specifically, the definition of surface roughness is given as follows:

\[
r = \left[ \frac{1}{L} \sum_{i=1}^{L} (h_i - \bar{h})^2 \right]^{1/2}
\]

where \( r \) denotes surface roughness, \( h_i, i = 1, 2, \ldots, L \), is the surface height at the \( i \)-th position in the unit of layer, \( L \) denotes the lattice size, and the surface mean height is given by \( \bar{h} = (1/L) \sum_{i=1}^{L} h_i \).

In addition to surface roughness, another quantity that also determines the surface morphology is the surface mean slope. In this work, the surface mean slope is defined as the RMS of the surface gradient profile as follows:

\[
m = \left[ \frac{1}{L} \sum_{i=1}^{L} h_s^2 \right]^{1/2}
\]

where \( m \) denotes the RMS slope and \( h_{s,i} \) is the surface slope at the \( i \)-th lattice site, which is a dimensionless variable. The surface slope, \( h_{s,i} \), is computed as follows:

\[
h_{s,i} = \frac{h_{i+1} - h_i}{1}
\]

Since the unit of height is layer and the distance between two adjacent particles (the diameter of particles) always equals to one layer, the denominator of \( h_{s,i} \) is always one. Due to the use of PBCs, the slope at the boundary lattice site \( (i=L) \) is computed as the slope between the last lattice site \( (h_L) \) and the first lattice site \( (h_1) \).

To investigate the open-loop properties of surface morphology, a set of kMC simulations is carried out at different \( w \) with \( T=800 \text{ K} \) and \( L=40,000 \). In particular, the continuous-time Monte-Carlo (CTMC) method is used in the kMC simulations. In this method, a list of events is constructed and an event is selected randomly with its respective probability. After the execution of the selected event, the list is updated based on the new lattice configuration. The following values are used for the parameters of the migration rate of Eq. (1), \( v_0 = 10^{13} \text{ s}^{-1} \), \( E_a = 3.4 \text{ eV} \) and \( E_n = 0 \text{ eV} \). Figs. 2 and 3 show that both atomic roughness and slope increase with time and will reach steady-state values at different time scales. Furthermore, both surface roughness and slope increase with total deposition rate \( w \).

To further investigate the open-loop properties of this two species simulation model, simulations are carried out with different deposition rate ratio between the two components. As shown in
One of the most important applications of our work is to simulate and control the deposition process of thin film solar cells in order to improve solar cell efficiency. However, the wavelength of visible light (400–700 nm) is much larger than the diameter of ZnO particles (≈0.3 nm) and thus, it is necessary to define an aggregate surface morphology at length scales comparable to visible light wavelength (Huang et al., 2011b); the same aggregation level is used for the TCO layer in this work. The definition of aggregate surface roughness and slope is given as follows:

$$r_i = \sqrt{\frac{1}{L/\Delta} \sum_{j=1}^{L/\Delta} (h_{i,j} - \bar{h}_i)^2}$$

$$m_i = \sqrt{\frac{1}{L/\Delta} \sum_{j=1}^{L/\Delta} \left( \frac{h_{i,j} - h_{i,j+1}}{\Delta} \right)^2}$$

The dynamics of aggregate roughness and slope are shown in Figs. 6 and 7. The simulation duration is \(t_f=200\,\text{s}\) and 100 independent simulations were carried out to calculate the expected values of aggregate surface roughness and slope (further increase of the number of independent simulations did not change the expected values). It is clear that at the aggregation length \(\Delta = 400\), both \(\langle r_i^2(t_f) \rangle\) and \(\langle m_i^2(t_f) \rangle\) are much smaller compared to their
3. Closed-form modeling and parameter estimation

3.1. Edward–Wilkinson type equation of aggregate surface height

Given the complexity of the two species deposition process and the need to control surface roughness and slope at spatial scales comparable to the wavelength of visible light, the direct
subject to the following periodic boundary conditions

\[ h_j(0,t) = h_j(L,t) \quad (9) \]

\[ \frac{\partial h_j}{\partial x}(0,t) = \frac{\partial h_j}{\partial x}(L,t) \quad (10) \]

and the initial condition

\[ h_j(x,0) = h_j^0(x) \quad (11) \]

where \( x \in [0,L] \) is the spatial coordinate, \( t \) is the time, \( h_j(x,t) \) is the aggregate surface height and \( \zeta(x,t) \) is a Gaussian white noise with zero mean and the following covariance:

\[ \langle \zeta(x,t)\zeta(x',t') \rangle = \sigma^2 \delta(x-x')\delta(t-t') \quad (12) \]

where \( \delta(\cdot) \) denotes the Dirac delta function. In Eq. (8), the parameters \( c_2 \) and \( \sigma^2 \), corresponding to diffusion effects and stochastic noise respectively, depend on the deposition rate \( w(x,t) \). In the case of a patterned deposition rate profile (control actuation), the term \( w(x,t) \) is of the form

\[ w(x,t) = w_0(t) + A(t) \sin \left( \frac{2kn\pi}{L} x \right) \quad (13) \]

where \( w_0(t) \) is the total mean deposition rate and \( A(t) \) is the total magnitude of patterned deposition rate. In the context of two species simulations, \( w(x,t) \), \( w_0(t) \) and \( A(t) \) can be seen as the sum of corresponding values from each component (i.e., \( w(x,t) = w_1(x,t) + w_2(x,t) \), \( w_0(t) = w_{1,0}(t) + w_{2,0}(t) \), \( A(t) = A_1(t) + A_2(t) \)) and \( k \) is the number of sine waves between 0 and \( L \).

To analyze the dynamics and obtain a solution to the EW equation suitable for real-time controller calculations, we first consider the eigenvalue problem of the linear operator of Eq. (8) subject to the periodic boundary conditions of Eqs. (9) and (10)

\[ A\tilde{\phi}_n(x) = c^2 \frac{d^2\tilde{\phi}_n(x)}{dx^2} = \lambda_n \tilde{\phi}_n(x) \quad (14) \]

\[ \nabla^j \tilde{\phi}_n(0) = \nabla^j \tilde{\phi}_n(L), \quad j = 0, 1 \quad (15) \]

where \( \lambda_n \) denotes an eigenvalue, \( \tilde{\phi}_n \) denotes an eigenfunction, and \( \nabla^j \), \( j = 0, 1 \), denotes the gradient of a given function. The solution of the eigenvalue problem of Eqs. (14) and (15) is as follows:

\[ \lambda_n = -4c_2 \pi^2 n^2 \frac{L}{L^2} \quad (16) \]

\[ \phi_{1,n}(x) = \phi_n = \sqrt{\frac{2}{L}} \sin \left( \frac{2\pi n x}{L} \right) \quad (17) \]

\[ \phi_{2,n}(x) = \psi_n = \begin{cases} \frac{1}{L} & n = 0 \\ \sqrt{\frac{2}{L}} \cos \left( \frac{2\pi n x}{L} \right) & n \neq 0 \end{cases} \quad (18) \]

The solution of the EW equation of Eq. (8) can be expanded in an infinite series in terms of the eigenfunctions of the spatial differential operator of Eq. (14) as follows:

\[ h_j(x,t) = \sum_{n=0}^{\infty} \left( \phi_{1,n}(x) z_{1,n}(t) + \phi_{2,n}(x) z_{2,n}(t) \right) \quad (19) \]

where \( z_{1,n}(t) \), \( z_{2,n}(t) \) are time-varying coefficients.

Substituting the above expansion for the solution, \( h_j(x,t) \), into Eq. (8) and taking the inner product with the adjoint eigenfunctions, the following system of infinite stochastic linear ordinary differential equations (ODEs) for the temporal evolution of the time-varying coefficients in Eq. (19) is obtained

\[ \frac{dz_{2,0}(t)}{dt} = w_{2,0} + \xi_{2,0}(t) \quad (20) \]
\[
\frac{dz_{p,n}(t)}{dt} = w_{p,n} + \zeta_p z_{p,n} + \tilde{\zeta}_{p,n}(t), \quad p = 1, 2, \quad n = 1, \ldots, \frac{L}{2A}.
\]  
(21)

where \(\tilde{\zeta}_{p,n}(t) = \int_0^t \zeta(x,t)\phi_{p,n}(x) \, dx\) is the projection of the noise \(\zeta(x,t)\) on the ODE for \(z_{p,n}\). The noise term, \(\tilde{\zeta}_{p,n}\), has zero mean and covariance

\[
\langle \tilde{\zeta}_{p,n}(t)\tilde{\zeta}_{p,n}(t') \rangle = \sigma^2 \delta(t - t').
\]

(22)

Similarly, \(w_{p,n}\) is the projection of \(w\) on the ODE for \(z_{p,n}(t)\), \(w_{p,n} = \int_0^t \phi_{p,n}(x)w(x) \, dx\)

- If \(p = 1\),
  \[
  w_{1,n} = \begin{cases} 
  0, & n \neq k \\
  A\sqrt{\frac{t}{2}}, & n = k 
  \end{cases}
  \]
  (23)

- If \(p = 2\),
  \[
  w_{2,n} = \begin{cases} 
  0, & n \neq 0 \\
  A\sqrt{t}, & n = 0 
  \end{cases}
  \]
  (24)

The temporal evolution of the variance of mode \(z_{p,n}\) can be obtained from the solution of the linear ODEs of Eqs. (20) and (21) as follows:

\[
\langle z_{2,0}(t) \rangle = w_{2,0}(t - t_0)
\]

(25)

\[
\text{var}(z_{2,0}(t)) = \sigma^2(t - t_0)
\]

(26)

\[
\langle z(t) \rangle = e^{\lambda(t-t_0)} \langle z(t_0) \rangle + \frac{w_0}{\lambda}(e^{\lambda(t-t_0)} - 1)
\]

(27)

\[
\text{var}(z(t)) = e^{2\lambda(t-t_0)} \text{var}(z(t_0)) + \sigma^2 e^{2\lambda(t-t_0)} - 1
\]

(28)

where \(z(t) = z_{p,n}(t)\), \(\lambda = \lambda_0\) and \(w_0 = w_{p,n}\) for \(n \neq 0\).

Finally, it is necessary to point out that, when aggregate (discrete) surface height profile is used, the highest number of modes that can be accurately estimated from \(h_i(x,t)\) is limited by the spatial sampling points, \(n \leq L/2A\); the reader may refer to Zhang et al. (2012) for a detailed discussion of the issue.

### 3.2. Aggregate surface root-mean-square roughness

Aggregate surface roughness of the thin film is defined as the standard deviation of the aggregate surface height profile from its average height

\[
r_{a}(t) = \sqrt{\frac{1}{L} \int_0^L [h_{a}(x,t) - \overline{h}_{a}(t)]^2 \, dx}
\]

(29)

where \(\overline{h}_{a}(t) = (1/L) \int_0^L h_{a}(x,t) \, dx\) is the average aggregate surface height. According to Eq. (19), we have

\[
\overline{h}_{a}(t) = \int_0^L \phi_{2,0} z_{2,0} \, dx = \sqrt{\frac{1}{L} \text{var}(z_{2,0})}
\]

(30)

Using that

\[
h_{a}(x,t) - \overline{h}_{a}(t) = \sum_{n=1}^{L/2A} \sum_{p=1}^2 \phi_{p,n}(x)z_{p,n}(t)
\]

(31)

and the expected aggregate surface roughness, \(\langle r_{a}^2(t) \rangle\), of Eq. (29) can be re-written as

\[
\langle r_{a}^2(t) \rangle = \int_0^L \left[ \sum_{p=1}^2 \sum_{n=1}^{L/2A} z_{p,n}(t) \phi_{p,n}(x) \right]^2 \, dx
\]

\[
= \int_0^L \left[ \sum_{n=1}^{L/2A} \left( \phi_{1,n}^2(x)z_{1,n}^2(t) + \phi_{2,n}^2(x)z_{2,n}^2(t) \right) \right] \, dx
\]

(32)

where

\[
\langle z_{p,n}^2 \rangle = \text{var}(z_{p,n}) + \langle z_{p,n} \rangle^2
\]

(33)

The expression of Eqs. (32) and (33) will be used in the MPC formulation; see Eq. (42) below.

### 3.3. Aggregate surface root-mean-square slope

The aggregate RMS slope is defined as the root-mean–square of the aggregate surface slope in the x-direction as follows:

\[
m_{a}(t) = \sqrt{\frac{1}{L} \int_0^L \frac{\partial h_{a}(x,t)}{\partial x}^2 \, dx} = \sqrt{\frac{1}{L} \sum_{i=0}^{L/4} \left( \frac{h_{a}(i+1,t) - h_{a}(i,t)}{A} \right)^2}
\]

(34)

Using the expansion of Eq. (19), Eq. (34) can be written as:

\[
\langle m_{a}^2(t) \rangle = \frac{1}{L} \sum_{i=0}^{L/4} \left( \frac{h_{a}(i+1,t) - h_{a}(i,t)}{A} \right)^2
\]

\[
= \frac{1}{L} \sum_{i=0}^{L/4} \left( \sum_{n=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \left( \phi_{p,n}(i) \phi_{p,n}(i) \right) \right)
\]

\[
= \frac{1}{L} \sum_{i=0}^{L/4} \left( \sum_{n=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \left( \phi_{p,n}(i) \phi_{p,n}(i) \right) \right)
\]

(35)

where

\[
\sum_{i=0}^{L/4} \phi_{p,n}(i) \phi_{p,n}(i)
\]

\[
= \sum_{i=0}^{L/4} (\phi_{p,n}(i+1) - \phi_{p,n}(i)) (\phi_{p,n}(i+1) - \phi_{p,n}(i))
\]

\[
= 2 \sum_{i=0}^{L/4} \left( \sin \left( \frac{2\pi i}{L/4} \right) \right)^2 \left( \sin \left( \frac{2\pi i}{L/4} \right) \right)^2
\]

\[
= \frac{8}{L} \sum_{i=0}^{L/4} \left( \cos \left( \frac{\pi}{L/4} (2i+1) \right) \right)
\]

(36)

or more compactly

\[
\langle m_{a}^2(t) \rangle = \frac{1}{L} \sum_{i=0}^{L/4} \left( \sum_{n=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \left( \phi_{p,n}(i) \phi_{p,n}(i) \right) \right)
\]

\[
= \frac{1}{L} \sum_{i=0}^{L/4} \left( \sum_{n=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \left( \phi_{p,n}(i) \phi_{p,n}(i) \right) \right)
\]

\[
= \frac{1}{L} \sum_{i=0}^{L/4} \left( \sum_{n=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \left( \phi_{p,n}(i) \phi_{p,n}(i) \right) \right)
\]

\[
= \frac{1}{L} \sum_{i=0}^{L/4} \left( \sum_{n=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \left( \phi_{p,n}(i) \phi_{p,n}(i) \right) \right)
\]

\[
= \frac{1}{L} \sum_{i=0}^{L/4} \left( \sum_{n=0}^{L/2A} \sum_{p=1}^2 \sum_{i=0}^{L/2A} \sum_{p=1}^2 \left( \phi_{p,n}(i) \phi_{p,n}(i) \right) \right)
\]

(37)
where
\[
K_{p,n} = \frac{8}{L^2 A} \sin^2 \left( \frac{n \pi}{L / A} \right) \sum_{i=0}^{L / (2A)} \left( \cos^2 \left( \frac{n \pi (2i+1)}{L / A} \right) \right)
\]
\[= \begin{cases} 
\frac{8}{L^2 A} \sin^2 \left( \frac{n \pi}{L / A} \right) & n = 0 \\
\frac{4}{L^2 A} \sin^2 \left( \frac{n \pi}{L / A} \right) & n \neq 0 
\end{cases}
\]

Finally, using that
\[
\sum_{i=0}^{L / (2A)} \left( \cos^2 \left( \frac{n \pi (2i+1)}{L / A} \right) \right) = \sum_{i=0}^{L / (2A)} \left( \frac{\cos(2n\pi(2i+1)/(L/4)+1)}{2} \right)
\]
\[= \begin{cases} 
\frac{L}{A} & n = 0 \\
\frac{L}{2A} & n \neq 0 
\end{cases}
\]

\[
\langle m_2'(t) \rangle \text{ can be expressed as}
\]
\[
\langle m_2(t) \rangle = \sum_{m=1}^{L / (2A)} (K_{1,m} \langle z_{1m}^2 \rangle + K_{2,m} \langle z_{2m}^2 \rangle)
\]

The expression of Eq. (40) will be used in the MPC formulation; see Eq. (42) below.

3.4. Parameter estimation

Referring to the EW equation of Eq. (8), there are two model parameters, \( c_2 \) and \( \sigma^2 \), that must be determined as functions of the total mean deposition rate \( w_0 \) and of the total patterned deposition rate magnitude \( A \). These parameters affect the dynamics of aggregate surface roughness and slope and can be estimated by fitting the predicted evolution profiles for aggregate surface roughness and slope from the EW equation to profiles of aggregate surface roughness and slope from kMC simulations. Least-square methods are used to estimate the model parameters so that the EW-model predictions are close in a least-square sense to the kMC simulation data. Comparison of the predictions of both models are shown in Fig. 12. Based on \( c_2 \) and \( \sigma^2 \) values obtained from these fitting results, different functions are chosen to estimate \( c_2 \) and \( \sigma^2 \) values at different \( w \) with the least-square method. Specifically, a linear function with respect to \( \log(w) \) is chosen to estimate \( \log(c_2) \) and a linear function with respect to \( w \) is chosen to estimate \( \sigma^2 \), and the expressions are given as follows:

\[
c_2(w) = w^{a_2} \cdot e^{b_2}
\]

\[
\sigma^2 = a_3 w + b_3
\]

where \( a_2, b_2, a_3, \text{ and } b_3 \) are time-invariant fitting model parameters. The fitting results are shown in Figs. 13 and 14. To verify the fitting function, two more groups of simulations are carried out with larger deposition rates \( w = 5 \) and \( 10 \text{ layer/s} \) and fitted to EW equation, and the obtained values for \( c_2 \) and \( \sigma^2 \) are used to extend the fitting curve to show the validity of the chosen fitting functions. It is necessary to clarify that these fitting results are based on kMC simulations with uniform deposition rate profiles \( (A=0) \). For simulations with patterned deposition rate profiles \( (A \neq 0) \), it is assumed that \( c_2 \) and \( \sigma^2 \) models obtained from uniform deposition rate

---

**Fig. 12.** Evolution of expected aggregate surface roughness with respect to time for different spatially uniform deposition rates obtained from kMC simulations (solid lines with symbols). The analytical solutions for the aggregate surface roughness obtained from the corresponding EW equations with the fitted values for \( c_2 \) and \( \sigma^2 \) are also shown (dashed lines).

**Fig. 13.** \( c_2 \) values for different spatially uniform deposition rates \( w \). The solid line is the result of a linear fitting function and it is the \( \log(c_2) \) versus \( \log(w) \) relationship used by the predictive controller. The first 5 blue cross-markers are used to generate the fitting function, and the last 2 red circle markers are used to test the validity of the fitting function. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

**Fig. 14.** \( \sigma^2 \) values for different spatially uniform deposition rates \( w \). The solid line is the result of a linear fitting function. The first 5 blue cross-markers are used to generate the fitting function, and the last 2 red circle markers are used to test the validity of the fitting function. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)
simulations \((A=0)\) can be used to estimate \(c_2\) and \(\sigma^2\) values. To verify this assumption, the solutions of EW equations for aggregate surface evolution with patterned deposition rate profile are obtained based on \(c_2\) and \(\sigma^2\) models from open-loop kMC data with uniform deposition rate, and these dynamic evolution profiles are compared with open-loop kMC dynamic evolution profiles with patterned deposition rate profiles. As shown in Figs. 15 and 16, \(c_2\) and \(\sigma^2\) models from open-loop kMC data with uniform deposition rate can be used in the EW equation to predict aggregate surface roughness and slope of the kMC model with patterned deposition rate. We note that the approach presented for the computation of the parameters of the closed-form PDE model of Eq. (8) is not limited to the specific PDE system and can be used in the context of other dissipative PDE systems that model the evolution of surface height of deposition processes. Finally, referring to the dependence of surface roughness and slope on lattice size, we note that both atomic and aggregate surface roughness and slope increase with increasing lattice size (this issue has been extensively studied in another work Huang et al., 2011a); however, the proposed approach to closed-form modeling and MPC design is scalable and can be used in the context of different lattice size kMC models as long as the parameters of the stochastic PDE model of Eq. (8) and their dependence on deposition rate are computed on the basis of data obtained from the lattice size considered.

4. Model predictive control

In this section, we design a model predictive controller based on the dynamic models of aggregate surface roughness and slope to simultaneously control the expected values of aggregate surface roughness and slope to desired levels. The dynamics of aggregate surface roughness and slope of the TCO thin film are described by the EW equation of aggregate surface height of Eq. (8) with the computed parameters of Section 3.4. State feedback control is considered in this work, i.e., \(h_i(x,t)\) is assumed to be available for feedback. In practice, real-time surface height measurements can be obtained via atomic force microscopy (AFM) systems.

4.1. MPC formulation for regulation of aggregate roughness and slope

We consider the problem of regulation of aggregate surface roughness and slope to desired levels within a model predictive control framework. Due to the stochastic nature of the variables, the expected values of aggregate surface roughness and slope, \(<r_j^2(t)\>\) and \(<m_j^2(t)\>\), are chosen as the control objectives. The total mean deposition rate, \(w_0\) \((w_0 = w_{1,0} + w_{2,0})\), and magnitude of patterned deposition rate, \(A (A = A_1 + A_2)\), are chosen as the manipulated inputs; the substrate temperature is fixed at \(T = 800\) K during all closed-loop simulations. To account for a number of practical considerations, several constraints are added to the control problem. In particular, since \(w(x) \geq 0\), the constraint \(0 \leq A_1 \leq w_{1,0}\) and \(0 \leq A_2 \leq w_{2,0}\) are imposed to ensure \(w(x,t) > 0, \forall(x,t)\). To ensure the validity of the closed-form process model, there is a constraint on the range of variation of the mean deposition rate. Another constraint is imposed on the rate of change of the mean deposition rate to account for actuator limitations. The control action at time \(t\) is obtained by solving a finite-horizon optimal control problem. The cost function in the optimal control problem includes penalty on the deviation of \(<r_j^2>\) and \(<m_j^2>\) from their respective set-point values. Different weighting factors are assigned to the aggregate surface roughness and slope. Aggregate surface roughness and slope have very different magnitudes, therefore, relative deviations are used in the formulation of the cost function to make the magnitude of the two terms comparable in the cost function. The optimization problem is subject to the dynamics of the aggregate surface height of Eq. (8). The optimal \(w_0\) and \(A\) values are calculated at each sampling time by solving a finite-dimensional optimization problem in a receding horizon fashion. Specifically, the MPC problem at time \(t\) is formulated as follows:

\[
\min_{w_0, A} f(w_0, A) = q_{r,j} \left[ \frac{r_{set}^2 - <r_j^2(t_f)>}{r_{set}^2} \right]^2 + q_{m,j} \left[ \frac{m_{set}^2 - <m_j^2(t_f)>}{m_{set}^2} \right]^2
\]

where

\[
<r_j^2(t_f)> = \frac{1}{I} \sum_{n=1}^{I} \sum_{p=1}^{2} <z_{p,n}^2(t_f)>,
\]

\[
<m_j^2(t_f)> = \frac{1}{I} \sum_{n=1}^{I} \sum_{p=1}^{2} (K_{p,n} <z_{p,n}^2(t_f)>)
\]
\[
\langle \Delta^2 \varphi_p(t_f) \rangle = \text{var}(\varphi_p(t_f)) + \langle \varphi_p(t_f) \rangle^2
\] (44)
\[
\langle \varphi_p(t_f) \rangle = e^{\Delta^2 \varphi_p(t_f)} \langle \varphi_p(t_f) \rangle + \frac{w^p}{\lambda_n} (e^{\Delta^2 \varphi_p(t_f)} - 1)
\] (45)
\[
\text{var}(\varphi_p(t_f)) = e^{2 \Delta^2 \varphi_p(t_f)} \text{var}(\varphi_p(t_f)) + \sigma^2(w) \frac{e^{2 \Delta^2 \varphi_p(t_f)} - 1}{2 \lambda_n}
\] (46)
\[
\lambda_n = -\frac{4c_{2y}(w)\pi^2}{L^2} n^2
\] (47)
and
\[
c_2(w_0) = c_{02} e^{b_2}
\] (48)
\[
\sigma^2(w_0) = a_{\text{max}} w_0 + b_\sigma
\] (49)
subject to:
\[
w_{\text{min}} \leq w_0 \leq w_{\text{max}}, \quad |w_0(t) - w_0(t-dt)| \leq \delta w_{\text{max}}
\] (50)
\[
w_1 = w_{1.0} + A_1 \sin \left(\frac{k_n x}{L}\right), \quad 0 \leq A_1 \leq w_{1.0}
\] (51)
\[
w_2 = w_{2.0} + A_2 \sin \left(\frac{k_n x}{L}\right), \quad 0 \leq A_2 \leq w_{2.0}
\] (52)

where \(t\) is the current time, \(dt\) is the sampling time, \(q_{w}\) and \(q_{w_0}\) are the weighting penalty factors for the deviations of \(\langle r_1^2 \rangle\) and \(\langle r_2^2 \rangle\), \(\text{var}(\varphi_p(t_f))\) from their respective set-points at the 4th prediction step, \(w_{\text{min}}\) and \(w_{\text{max}}\) are the lower and upper bounds on the mean deposition rate, respectively, and \(\delta w_{\text{max}}\) is the limit on the rate of change of the mean deposition rate. Given the batch nature of the deposition process, the MPC of Eq. (42) includes penalty on the discrepancy of the expected surface roughness and slope at the end of the deposition from the set-points values of surface roughness and slope that lead to desired film reflectance levels. The prediction horizon used in the MPC is the time duration from the current time \(t\) to the final time \(t_f\) but only one optimal manipulated input value is computed and it is implemented from \(t\) to \(t+dt\).

The optimal control actions are obtained from the solution of the multivariable optimization problem of Eq. (42) and are applied to the deposition process model over \(dt\) (i.e., either the EW equation model or the kMC model) during the time interval \((t, t + dt)\). At time \(t + dt\), a new measurement of aggregate surface roughness and slope is received by the controller and the MPC problem of Eq. (42) is solved for the next set of control actions. An interior point method optimizer, IPOPT (Wächter and Biegler, 2006), is used to solve the optimization problem in the MPC formulation and compute a locally optimal solution. With respect to the stability of the closed-loop system, we note the following: the deposition process is considered including atom adsorption and atom migration is an inherently stable process; this is evident by the negative values of all the eigenvalues of the spatial differential operator of the Edwards–Wilkinson type equation (Eq. (8)) used to model the evolution of surface height for all values of the deposition rate. Given this stability property of the open-loop process and the specific MPC design, the stability of the closed-loop system is ensured.

### 5. Simulation results

In this section, the model predictive controller of Eq. (42) is applied to both the one-dimensional EW equation type model of Eq. (8) and the one-dimensional kMC model of the thin film growth process. The mean deposition rate ranges from 0.1 to 2 layer/s, the substrate temperature is fixed at 800 K, the lattice size of the kMC model is fixed at 40,000 sites, the aggregation size is fixed at 400 to make the results relevant to thin film solar cell applications and five sine waves are used in the patterned deposition rate profile. The sampling time is 10 s; this sampling time is enough for the MPC to carry out the calculations needed to compute the control action. In addition to the deposition rate, the temperature may be used as a manipulated input but it should vary in space to induce substantial aggregate surface roughness and slope values at spatial scales corresponding to the visible light wavelength. Each closed-loop simulation lasts for 200 s. Expected values are computed from 10 independent closed-loop system simulation runs. In all the simulations, the aggregate surface roughness and slope set-points remain the same, specifically, \(r_{\text{set}}^2 = 1000\) and \(m_{\text{set}}^2 = 0.005\).

#### 5.1. MPC application to EW equation model

In this subsection, the EW equation model is utilized in the closed-loop control problem as the plant model. First, the problem of regulating aggregate surface roughness is considered. In this problem, the cost function includes only penalty on the deviation of the expected aggregate surface roughness square from its set-point, i.e., \(q_{w_1} = 1\) and \(q_{w_2} = 0\). Fig. 17 shows the evolution profile of \(\langle r_1^2(t) \rangle\) under the model predictive controller of Eq. (42). It is clear that the controller drives the expected aggregate surface roughness to its set-point at the end of the simulation. Fig. 18 shows the input profiles of \(w_0\) and \(A\) for these simulations. It is necessary to point out that during the first 40 s of the simulation time, the optimal solutions of \(w_0\) are constrained by the rate of change constraint and the optimal solutions of \(A\) are bounded by the values of \(w_0\).

Next, the aggregate surface slope is regulated. The cost function includes only penalty on the deviation of the expected value of aggregate surface slope square from its set-point \((q_{w_1} = 1, q_{w_2} = 0\). Fig. 19 shows the evolution profile of the expected aggregate slope square. The aggregate slope reaches its set-point at \(t = 200\) s. Fig. 20 displays the input profile in this scenario.

The next step is the simultaneous regulation of aggregate surface roughness and slope. The weighting factor of aggregate slope square, \(q_{w_1}\), is kept at 1, while the weighting factor of aggregate roughness square, \(q_{w_2}\), increases from \(10^{-2}\) to \(10^9\). Fig. 21 shows the values of expected aggregate surface roughness and slope at the end of closed-loop simulations \((t_f = 200\) s) as a function of \(q_{w_1}/q_{w_2}\). It can be seen that as the weighting on aggregate roughness increases, the expected value of aggregate roughness approaches its set-point at the cost of larger deviation of the aggregate slope from its set-point.

![Fig. 17. Profile of expected aggregate surface roughness square with EW equation as the plant model. \(q_{w_1} = 1, q_{w_2} = 0\) and \(r_{\text{set}}^2 = 1000\).](image-url)
5.2. MPC application to kMC model

In this subsection, the kMC model is used in the closed-loop control problem as the plant model, while all the other settings remain the same. Fig. 22 shows the aggregate surface roughness in the case of roughness-only control while Fig. 23 shows the aggregate surface slope in the case of slope-only control. From both plots, we see that both aggregate roughness and slope successfully reach their set-points at the end of the simulations (\(t_f = 200\) s). Furthermore, the closed-loop evolution profiles with kMC as the plant model are very similar to the closed-loop profiles that use the EW equation as the plant model, which implies that the EW equation model used in this work can accurately predict the kMC simulation results.

Simultaneous regulation of aggregate surface roughness and slope has also been investigated. Similar to the case where the EW equation is used as the plant model, the weighting factor of aggregate slope square, \(q_{m2}\), is kept at 1, and the weighting factor of aggregate roughness square, \(q_{m1}\), ranges from \(10^{-2}\) to \(10^4\). Fig. 24 shows the values of expected aggregate roughness and slope at the end of simulations as a function of \(q_{m2}/q_{m1}\). It can be seen that the expected value of aggregate roughness approaches its set-point as \(q_{m2}\) increases at the cost of larger deviation of the aggregate slope from its set-point.
lengths comparable to the wavelength of visible light. A model predictive controller is designed to regulate aggregate surface roughness and slope to desired levels, and the controller is applied to the EW equation and the kMC model of the deposition process with $L=40,000$. Simulation results demonstrate the applicability and effectiveness of the controller and of the spatially patterned deposition rate profile. The results of this work pave the way for the manufacturing of TCO layers with desired light trapping properties.

6. Conclusions

In this work, a two species thin film deposition process is simulated via a kinetic Monte–Carlo method in a large square lattice ($L=40,000$). Different growth mechanisms are used for each species (ZnO and Al) and a patterned deposition rate profile is introduced to generate significant aggregate surface roughness and slope at a length scale comparable to the wavelength of visible light. An Edwards–Wilkinson type equation for the aggregate surface profile is used to predict the surface temporal evolution of aggregate surface roughness and slope. A model predictive controller is designed to regulate aggregate surface roughness and slope to desired levels, and the controller is applied to the EW equation and the kMC model of the deposition process with $L=40,000$. Simulation results demonstrate the applicability and effectiveness of the controller and of the spatially patterned deposition rate profile. The results of this work pave the way for the manufacturing of TCO layers with desired light trapping properties.

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